



Precision Monolithic Quad SPST CMOS Analog Switches

FEATURES

- 44-V Supply Max Rating
- ± 15 -V Analog Signal Range
- On-Resistance— $r_{DS(on)}$: 25 Ω
- Fast Switching— t_{ON} : 110 ns
- Ultra Low Power— P_D : 0.35 μ W
- TTL, CMOS Compatible
- Single Supply Capability

BENEFITS

- Widest Dynamic Range
- Low Signal Errors and Distortion
- Break-Before-Make Switching Action
- Simple Interfacing

APPLICATIONS

- Precision Automatic Test Equipment
- Precision Data Acquisition
- Communication Systems
- Battery Powered Systems
- Computer Peripherals

DESCRIPTION

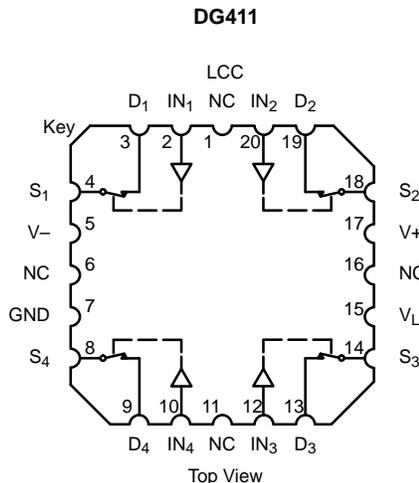
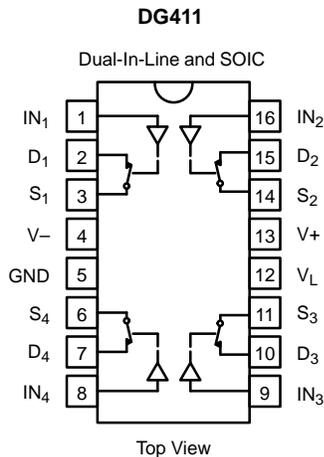
The DG411 series of monolithic quad analog switches was designed to provide high speed, low error switching of precision analog signals. Combining low power (0.35 μ W) with high speed (t_{ON} : 110 ns), the DG411 family is ideally suited for portable and battery powered industrial and military applications.

Each switch conducts equally well in both directions when on, and blocks input voltages up to the supply levels when off.

The DG411 and DG412 respond to opposite control logic as shown in the Truth Table. The DG413 has two normally open and two normally closed switches.

To achieve high-voltage ratings and superior switching performance, the DG411 series was built on Vishay Siliconix's high voltage silicon gate process. An epitaxial layer prevents latchup.

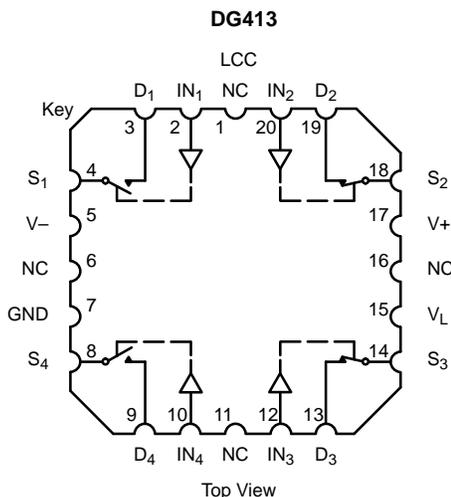
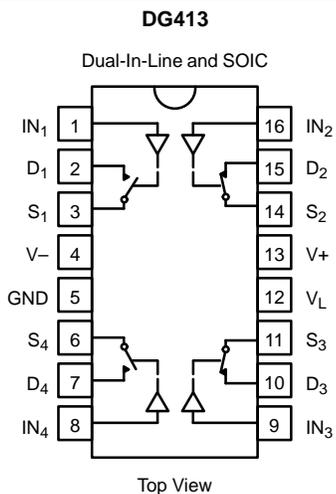
FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



| TRUTH TABLE | | |
|-------------|-------|-------|
| Logic | DG411 | DG412 |
| 0 | ON | OFF |
| 1 | OFF | ON |

Logic "0" ≤ 0.8 V
 Logic "1" ≥ 2.4 V

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



| TRUTH TABLE | | |
|-------------|-----------------------------------|-----------------------------------|
| Logic | SW ₁ , SW ₄ | SW ₂ , SW ₃ |
| 0 | OFF | ON |
| 1 | ON | OFF |

Logic "0" ≤ 0.8 V
Logic "1" ≥ 2.4 V

| ORDERING INFORMATION | | |
|----------------------|--------------------|---------------------------------------|
| Temp Range | Package | Part Number |
| DG411/412 | | |
| -40 to 85°C | 16-Pin Plastic DIP | DG411DJ |
| | | DG412DJ |
| -40 to 85°C | 16-Pin Narrow SOIC | DG411DY |
| | | DG412DY |
| -55 to 125°C | 16-Pin CerDIP | DG411AK, DG411AK/883, 5962-9073101MEA |
| | | DG412AK, DG412AK/883, 5962-9073102MEA |
| | LCC-20 | DG411AZ/883, 5962-9073101M2A |
| | | 5962-9073102M2A |
| DG413 | | |
| -40 to 85°C | 16-Pin Plastic DIP | DG413DJ |
| | 16-Pin Narrow SOIC | DG413DY |
| -55 to 125°C | 16-Pin CerDIP | DG413AK, DG413AK/883, 5962-9073103MEA |
| | LCC-20 | 5962-9073103M2A |

ABSOLUTE MAXIMUM RATINGS

| | |
|---|---|
| V+ to V- | 44 V |
| GND to V- | 25 V |
| V _L | (GND -0.3 V) to (V+) +0.3 V |
| Digital Inputs ^a , V _S , V _D | (V-) -2 V to (V+) +2 V or 30 mA, whichever occurs first |
| Continuous Current (Any Terminal) | 30 mA |
| Peak Current, S or D (Pulsed 1 ms, 10% Duty Cycle) | 100 mA |
| Storage Temperature | (AK, AZ Suffix) -65 to 150°C |
| | (DJ, DY Suffix) -65 to 125°C |

| | |
|--|--------|
| Power Dissipation (Package) ^b | |
| 16-Pin Plastic DIP ^c | 470 mW |
| 16-Pin Narrow SOIC ^d | 600 mW |
| 16-Pin CerDIP ^e | 900 mW |
| LCC-20 ^e | 900 mW |

Notes:

- Signals on S_X, D_X, or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- All leads welded or soldered to PC Board.
- Derate 6 mW/°C above 25°C
- Derate 7.6 mW/°C above 75°C
- Derate 12 mW/°C above 75°C



| SPECIFICATIONS ^a | | | | | | | | | |
|--|---------------------|---|-------------------|------------------|--------------------------|------------------|-------------------------|------------------|------|
| Parameter | Symbol | Test Conditions Unless Specified V ₊ = 15 V, V ₋ = -15 V V _L = 5 V, V _{IN} = 2.4 V, 0.8 V ^f | Temp ^b | Typ ^c | A Suffix -55 to 125°C | | D Suffix -40 to 85°C | | Unit |
| | | | | | Min ^d | Max ^d | Min ^d | Max ^d | |
| Analog Switch | | | | | | | | | |
| Analog Signal Range ^e | V _{ANALOG} | | Full | | -15 | 15 | -15 | 15 | V |
| Drain-Source On-Resistance | r _{DS(on)} | V ₊ = 13.5 V, V ₋ = -13.5 V I _S = -10 mA, V _D = ± 8.5 V | Room Full | 25 | | 35 45 | | 35 45 | Ω |
| Switch Off Leakage Current | I _{S(off)} | V ₊ = 16.5 V, V ₋ = -16.5 V V _D = ± 15.5 V, V _S = ∓ 15.5 V | Room Full | ± 0.1 | -0.25 -20 | 0.25 20 | -0.25 -5 | 0.25 5 | nA |
| | I _{D(off)} | | Room Full | ± 0.1 | -0.25 -20 | 0.25 20 | -0.25 -5 | 0.25 5 | |
| Channel On Leakage Current | I _{D(on)} | V ₊ = 16.5 V, V ₋ = -16.5 V V _S = V _D = ± 15.5 V | Room Full | ± 0.1 | -0.4 -40 | 0.4 40 | -0.4 -10 | 0.4 10 | |
| Digital Control | | | | | | | | | |
| Input Current, V _{IN} Low | I _{IL} | V _{IN} Under Test = 0.8 V | Full | 0.005 | -0.5 | 0.5 | -0.5 | 0.5 | μA |
| Input Current, V _{IN} High | I _{IH} | V _{IN} Under Test = 2.4 V | Full | 0.005 | -0.5 | 0.5 | -0.5 | 0.5 | |
| Dynamic Characteristics | | | | | | | | | |
| Turn-On Time | t _{ON} | R _L = 300 Ω, C _L = 35 pF V _S = ± 10 V See Figure 2 | Room Full | 110 | | 175 240 | | 175 220 | ns |
| Turn-Off Time | t _{OFF} | | Room Full | 100 | | 145 160 | | 145 160 | |
| Break-Before-Make Time Delay | t _D | DG413 Only, V _S = 10 V R _L = 300 Ω, C _L = 35 pF | Room | 25 | | | | | |
| Charge Injection | Q | V _g = 0 V, R _g = 0 Ω, C _L = 10 nF | Room | 5 | | | | | pC |
| Off Isolation ^e | OIRR | R _L = 50 Ω, C _L = 5 pF, f = 1 MHz | Room | 68 | | | | | dB |
| Channel-to-Channel Cross-talk ^e | X _{TALK} | | Room | 85 | | | | | |
| Source Off Capacitance ^e | C _{S(off)} | f = 1 MHz | Room | 9 | | | | | pF |
| Drain Off Capacitance ^e | C _{D(off)} | | Room | 9 | | | | | |
| Channel On Capacitance ^e | C _{D(on)} | | Room | 35 | | | | | |
| Power Supplies | | | | | | | | | |
| Positive Supply Current | I ₊ | V ₊ = 16.5 V, V ₋ = -16.5 V V _{IN} = 0 or 5 V | Room Full | 0.0001 | | 1 5 | | 1 5 | μA |
| Negative Supply Current | I ₋ | | Room Full | -0.0001 | -1 -5 | | -1 -5 | | |
| Logic Supply Current | I _L | | Room Full | 0.0001 | | 1 5 | | 1 5 | |
| Ground Current | I _{GND} | | Room Full | -0.0001 | -1 -5 | | -1 -5 | | |

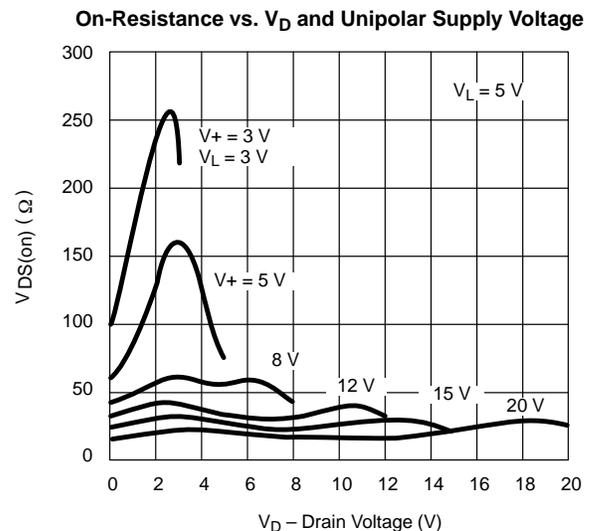
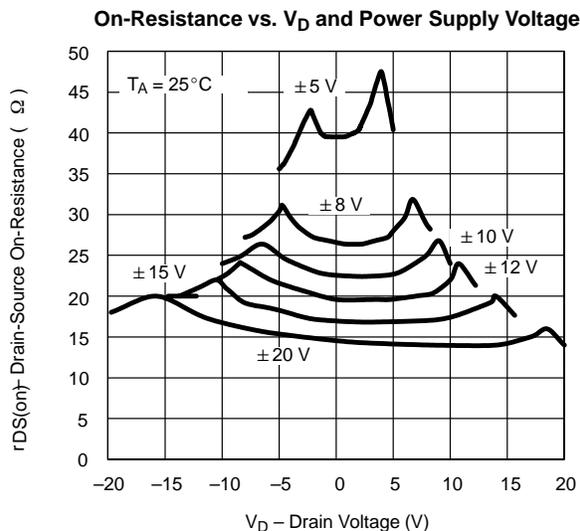


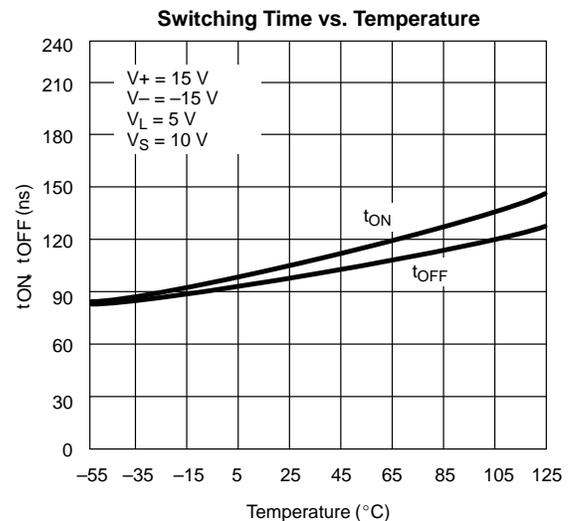
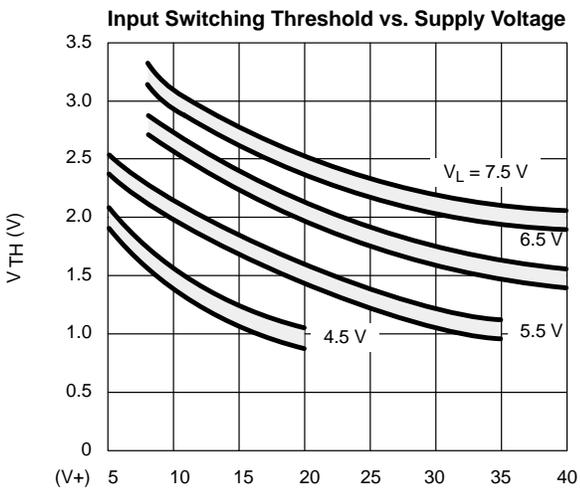
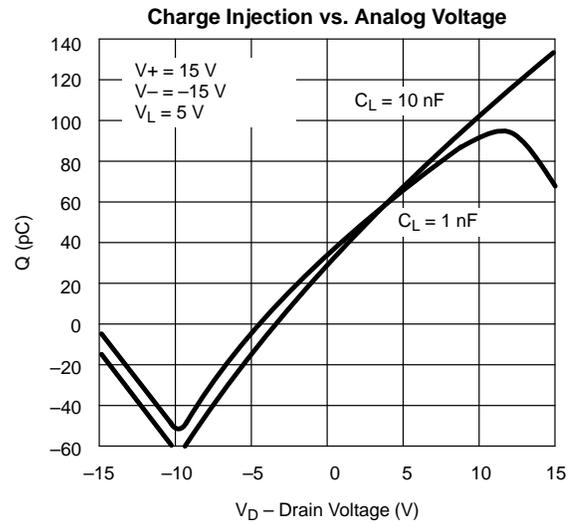
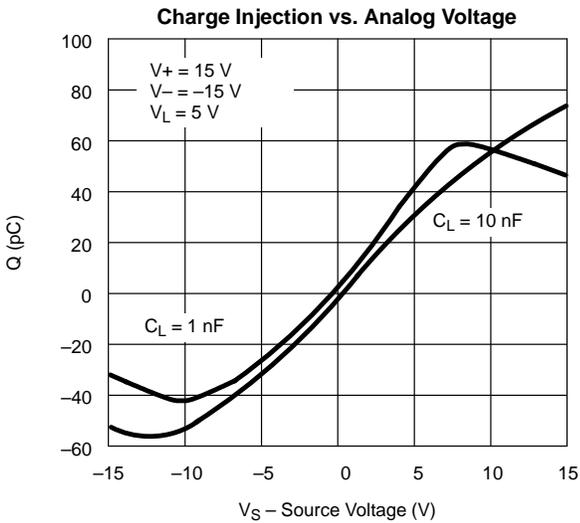
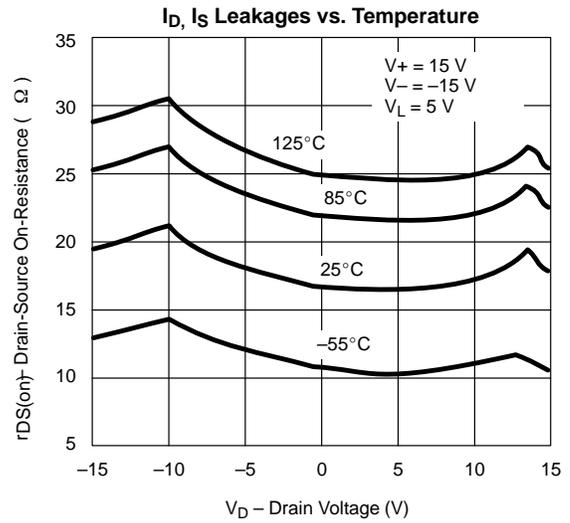
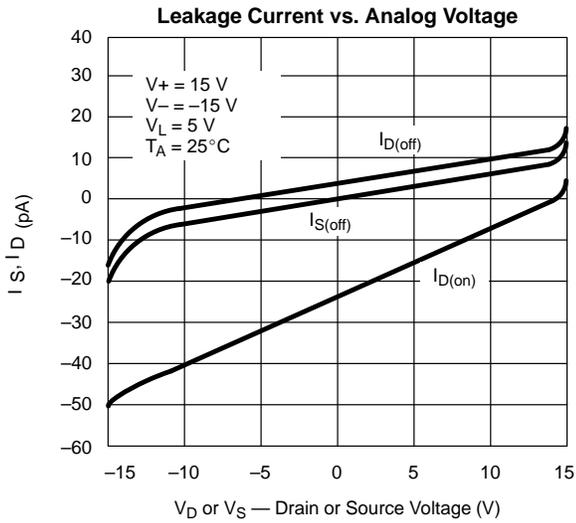
| SPECIFICATIONS ^a FOR UNIPOLAR SUPPLIES | | | | | | | | | |
|---|--------------|--|-------------------|------------------|--------------------------|------------------|-------------------------|------------------|---------------|
| Parameter | Symbol | Test Conditions Unless Specified $V_+ = 12\text{ V}, V_- = 0\text{ V}$ $V_L = 5\text{ V}, V_{IN} = 2.4\text{ V}, 0.8\text{ V}^f$ | Temp ^b | Typ ^c | A Suffix -55 to 125°C | | D Suffix -40 to 85°C | | Unit |
| | | | | | Min ^d | Max ^d | Min ^d | Max ^d | |
| Analog Switch | | | | | | | | | |
| Analog Signal Range ^e | V_{ANALOG} | | Full | | | 12 | | 12 | V |
| Drain-Source On-Resistance | $r_{DS(on)}$ | $V_+ = 10.8\text{ V}, I_S = -10\text{ mA}$ $V_D = 3\text{ V}, 8\text{ V}$ | Room Full | 40 | | 80 100 | | 80 100 | Ω |
| Dynamic Characteristics | | | | | | | | | |
| Turn-On Time | t_{ON} | $R_L = 300\ \Omega, C_L = 35\text{ pF}$ $V_S = 8\text{ V}, \text{ See Figure 2}$ | Room Hot | 175 | | 250 400 | | 250 315 | ns |
| Turn-Off Time | t_{OFF} | | Room Hot | 95 | | 125 140 | | 125 140 | |
| Break-Before-Make Time Delay | t_D | DG413 Only, $V_S = 8\text{ V}$, $R_L = 300\ \Omega, C_L = 35\text{ pF}$ | Room | 25 | | | | | |
| Charge Injection | Q | $V_g = 6\text{ V}, R_g = 0\ \Omega, C_L = 10\text{ nF}$ | Room | 25 | | | | | pC |
| Power Supplies | | | | | | | | | |
| Positive Supply Current | I_+ | $V_+ = 13.5\text{ V}, V_{IN} = 0\text{ or }5\text{ V}$ | Room Hot | 0.0001 | | 1 5 | | 1 5 | μA |
| Negative Supply Current | I_- | | Room Hot | -0.0001 | -1 -5 | | -1 -5 | | |
| Logic Supply Current | I_L | | Room Hot | 0.0001 | | 1 5 | | 1 5 | |
| Ground Current | I_{GND} | | Room Hot | -0.0001 | -1 -5 | | -1 -5 | | |

Notes:

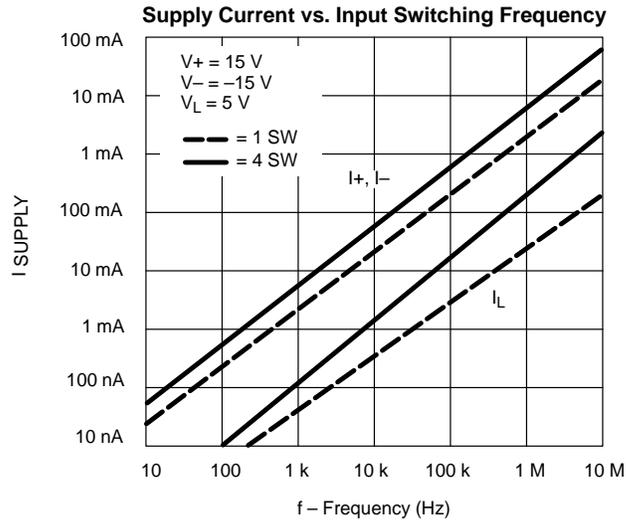
- a. Refer to PROCESS OPTION FLOWCHART.
- b. Room = 25°C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.
- f. V_{IN} = input voltage to perform proper function.

TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)


TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



SCHEMATIC DIAGRAM (TYPICAL CHANNEL)

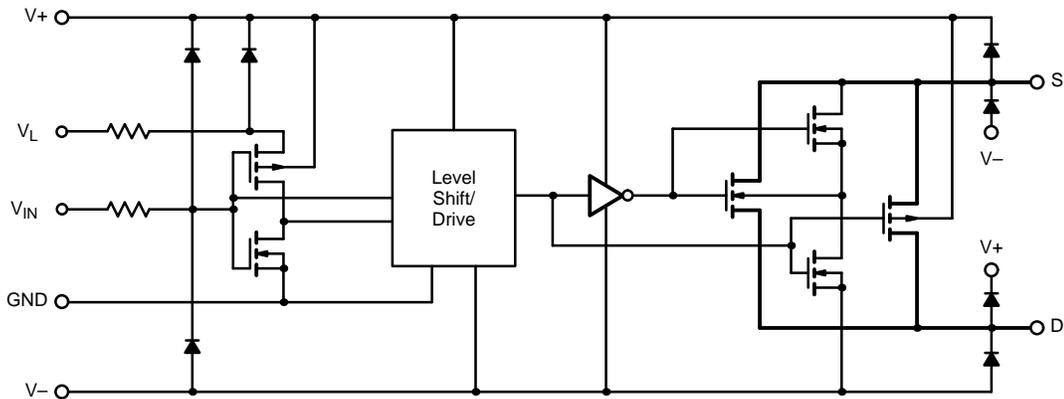
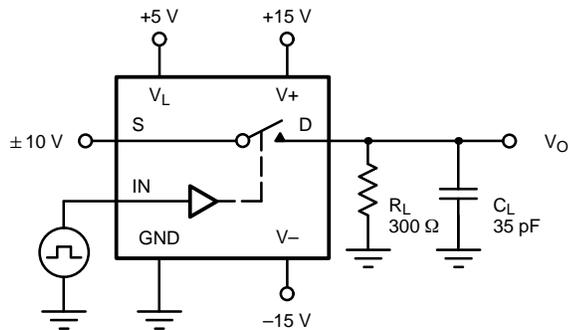


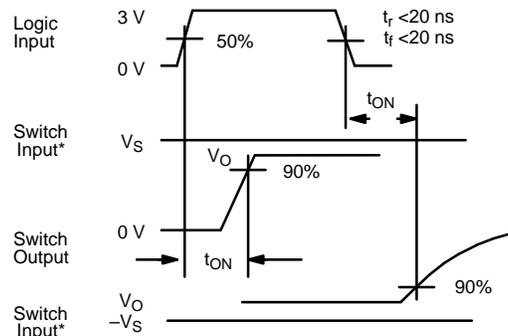
FIGURE 1.

TEST CIRCUITS



C_L (includes fixture and stray capacitance)

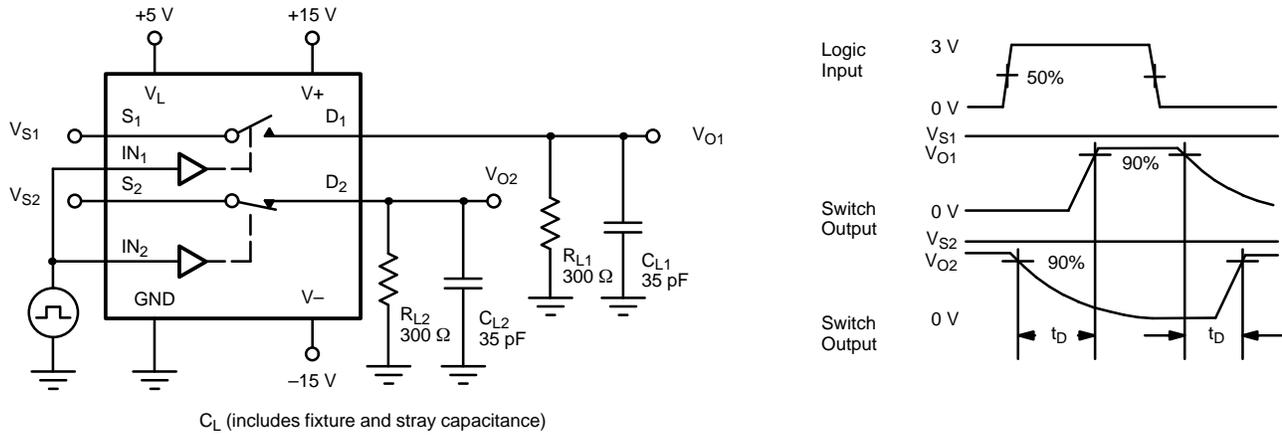
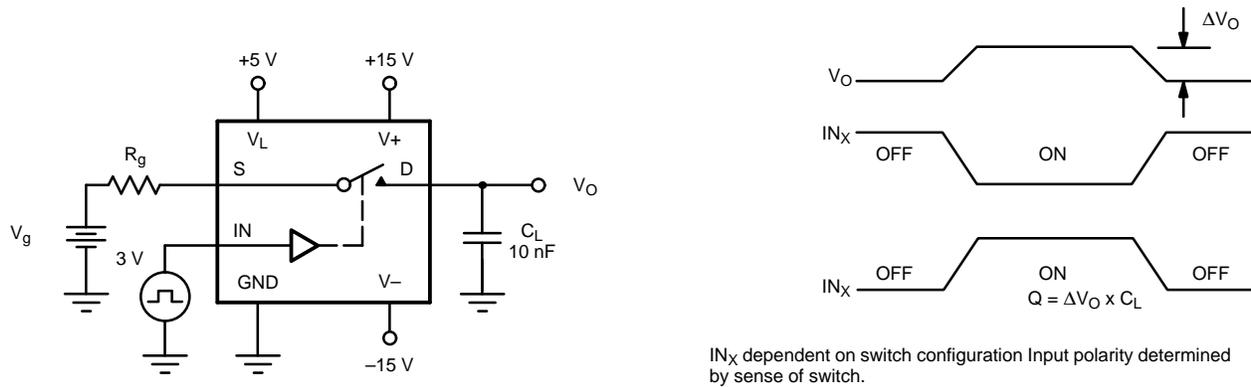
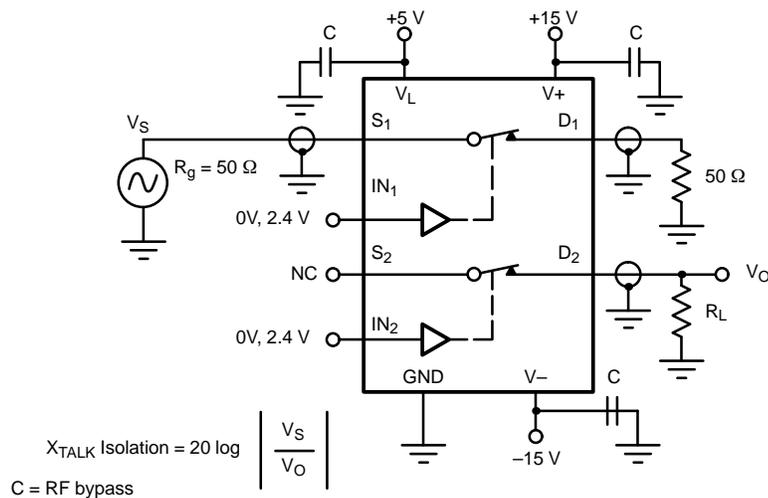
$$V_O = V_S \frac{R_L}{R_L + r_{DS(on)}}$$



* $V_S = 10\text{ V}$ for t_{ON} , $V_S = -10\text{ V}$ for t_{OFF}

Note: Logic input waveform is inverted for switches that have the opposite logic sense control

FIGURE 2. Switching Time

TEST CIRCUITS

FIGURE 3. Break-Before-Make (DG413)

FIGURE 4. Charge Injection

FIGURE 5. Crosstalk

TEST CIRCUITS

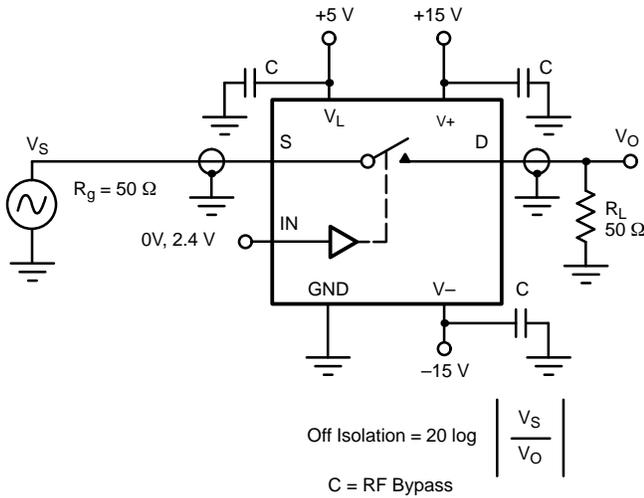


FIGURE 6. Off Isolation

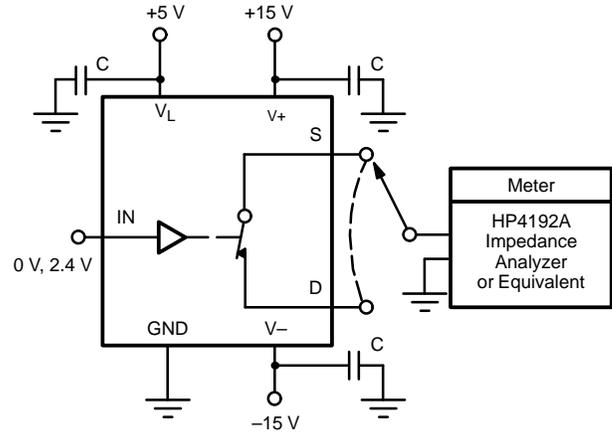


FIGURE 7. Source/Drain Capacitances

APPLICATIONS

Single Supply Operation:

The DG411/412/413 can be operated with unipolar supplies from 5 V to 44 V. These devices are characterized and tested for unipolar supply operation at 12 V to facilitate the majority of applications. In single supply operation, V+ is tied to VL and V- is tied to 0 V. See Input Switching Threshold vs. Supply Voltage curve for VL versus input threshold requirements.

Summing Amplifier

When driving a high impedance, high capacitance load such as shown in Figure 8, where the inputs to the summing amplifier have some noise filtering, it is necessary to have shunt switches for rapid discharge of the filter capacitor, thus preventing offsets from occurring at the output.

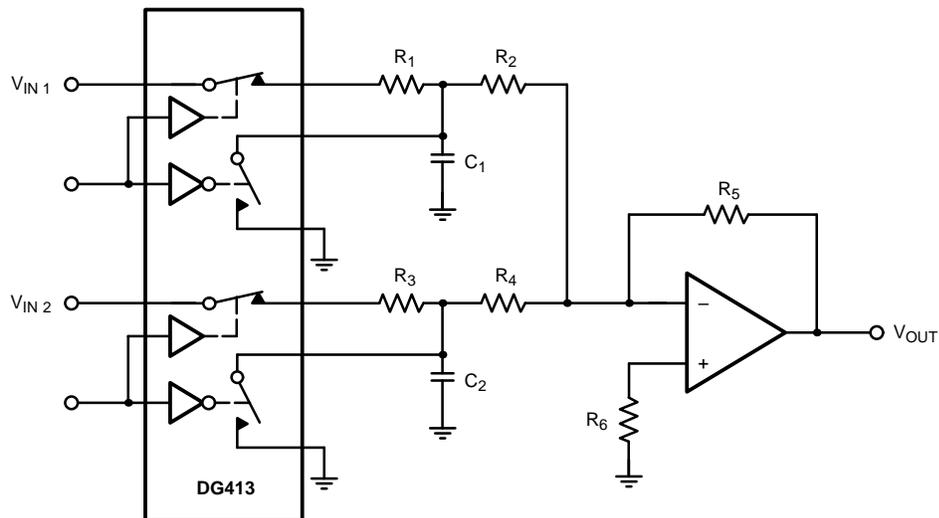


FIGURE 8. Summing Amplifier